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Tx 270318 ANSUSE I -**FAST RECOVERY DIODE****ARF2012**

Repetitive voltage up to

2600 V

Mean forward current

1525 A

Surge current

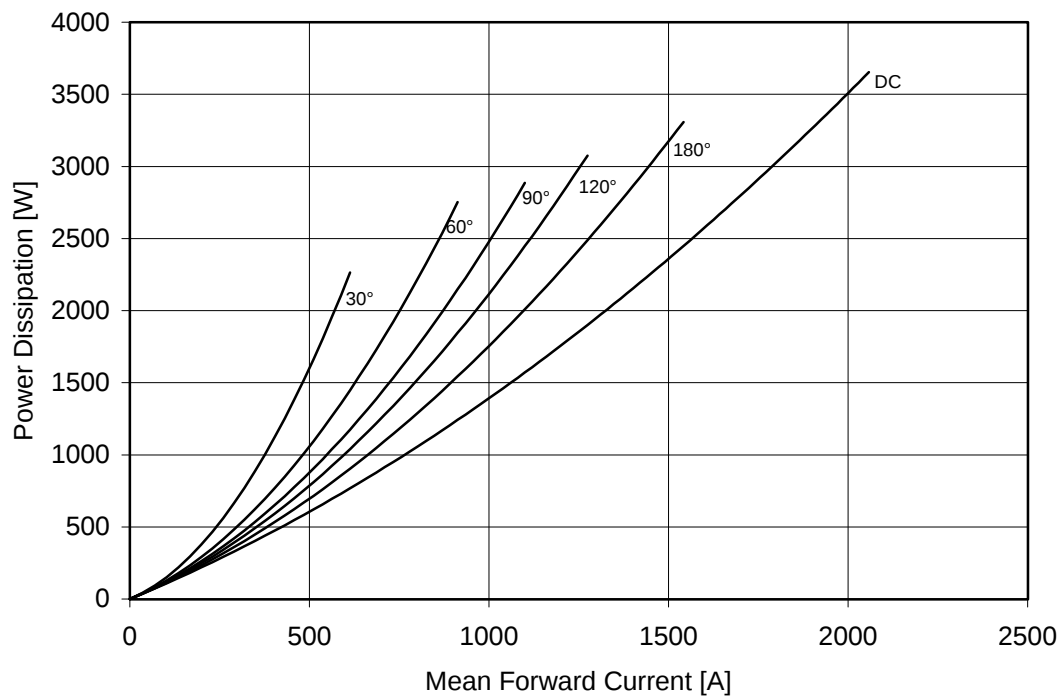
16 kA**FINAL SPECIFICATION**

apr 97 - ISSUE : 04

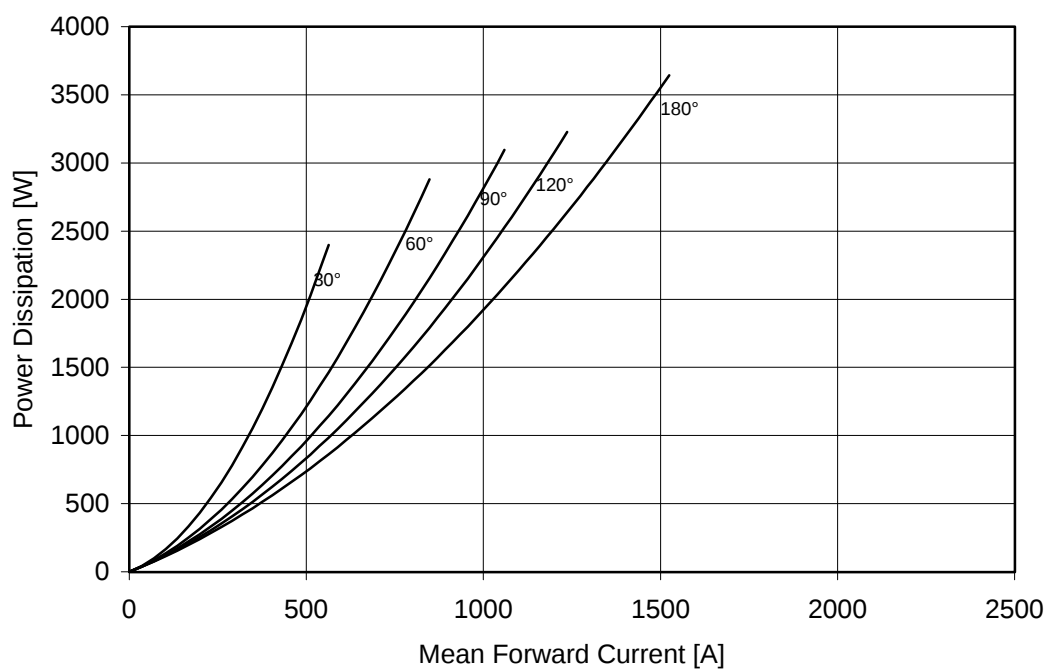
Symbol	Characteristic	Conditions	T _j [°C]	Value	Unit
BLOCKING					
V _{RRM}	Repetitive peak reverse voltage		150	2600	V
V _{RSM}	Non-repetitive peak reverse voltage		150	2700	V
I _{RRM}	Repetitive peak reverse current	V=VRRM	150	50	mA
CONDUCTING					
I _{F(AV)}	Mean forward current	180° sin ,50 Hz, Th=55°C, double side cooled		1525	A
I _{F(AV)}	Mean forward current	180° square,50 Hz,Th=55°C,double side cooled		1545	A
I _{FSM}	Surge forward current	Sine wave, 10 ms	150	16	kA
I ² t	I ² t	reapplied reverse voltage up to 50% VRSM		1280 x1E3	A²s
V _{FM}	Forward voltage	Forward current 3400 A	25	2.5	V
V _{F(TO)}	Threshold voltage		150	1.03	V
r _F	Forward slope resistance		150	0.362	mohm
SWITCHING					
t _{rr}	Reverse recovery time	I _F = 1000 A di/dt= 100 A/μs VR = 100 V	150	4.6	μs
Q _{rr}	Reverse recovery charge			800	μC
I _{rr}	Peak reverse recovery current			345	A
s	Softness (s-factor), min			0.4	
V _{FR}	Peak forward recovery	di/dt= 400 A/μs	150	13	V
MOUNTING					
R _{th(j-h)}	Thermal impedance	Junction to heatsink, double side cooled		26	°C/kW
T _j	Operating junction temperature			-30 / 150	°C
F	Mounting force			18.0 / 20.0	kN
	Mass			500	g
ORDERING INFORMATION : ARF2012 S 26					
standard specification ☐ ☐ VRRM/100					

DISSIPATION CHARACTERISTICS

SQUARE WAVE

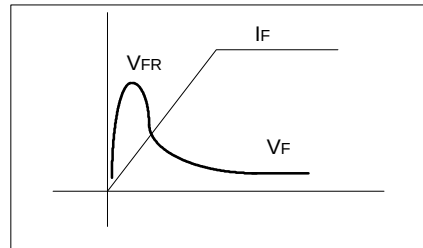
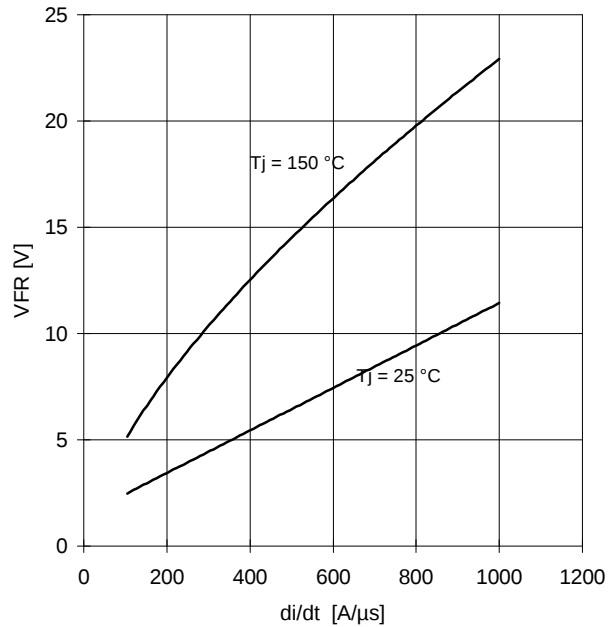
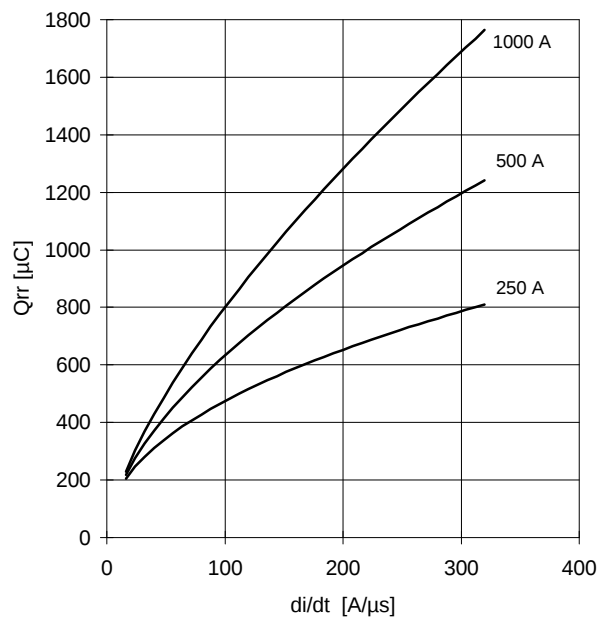
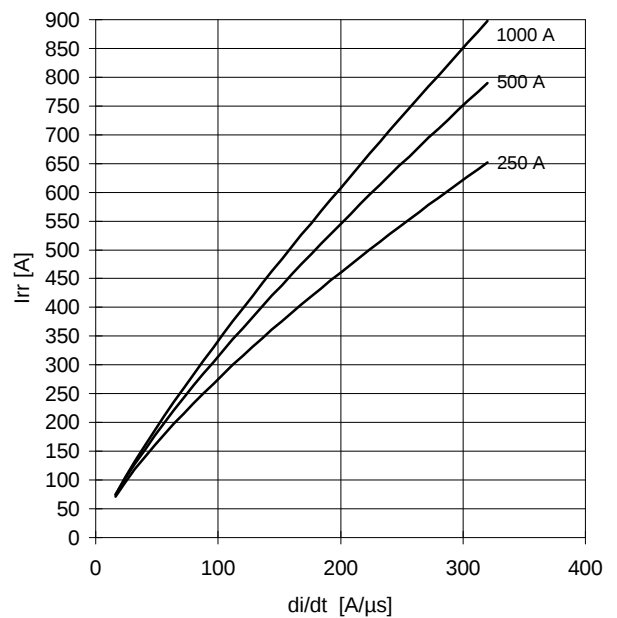


SINE WAVE



SWITCHING CHARACTERISTICS

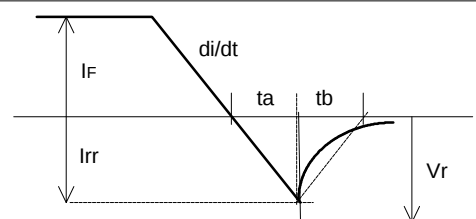
FORWARD RECOVERY VOLTAGE

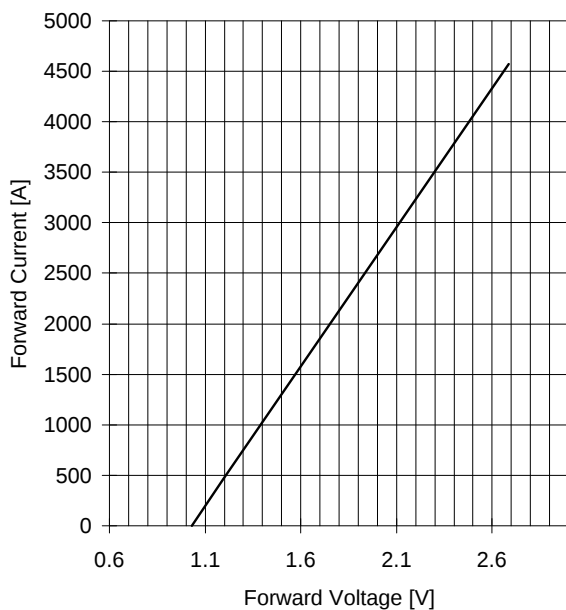
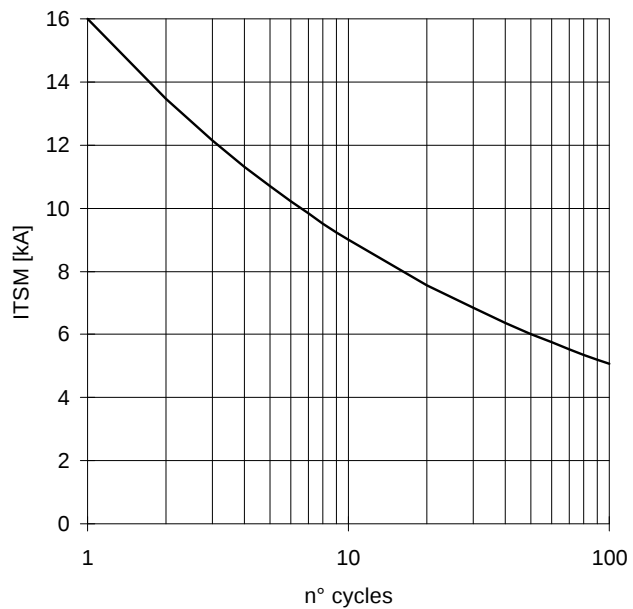
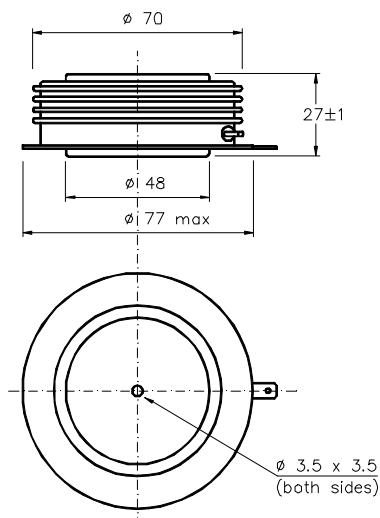
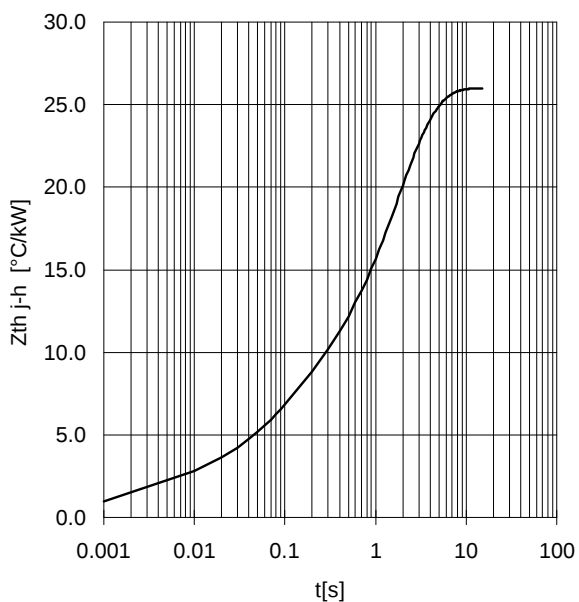
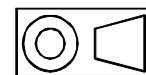
REVERSE RECOVERY CHARGE
 $T_j = 150\text{ }^{\circ}\text{C}$ REVERSE RECOVERY CURRENT
 $T_j = 150\text{ }^{\circ}\text{C}$ 

$$t_a = I_{rr} / (di/dt) \quad t_b = t_{rr} - t_a$$

$$\text{Softness (s factor)} \quad s = t_b / t_a$$

$$\text{Energy dissipation during recovery } E_r = V_r \cdot (Q_{rr} - I_{rr} \cdot t_a / 2)$$



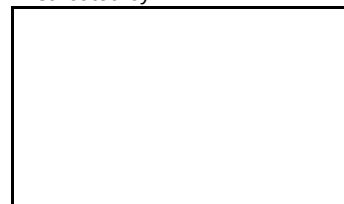
FORWARD CHARACTERISTIC
 $T_j = 150\text{ }^{\circ}\text{C}$ SURGE CHARACTERISTIC
 $T_j = 150\text{ }^{\circ}\text{C}$ TRANSIENT THERMAL IMPEDANCE
DOUBLE SIDE COOLEDDimensions
in mm

All the characteristics given in this data sheet are guaranteed only with uniform clamping force, cleaned and lubricated heatsink, surfaces with flatness $< .03\text{ mm}$ and roughness $< 2\text{ }\mu\text{m}$.

In the interest of product improvement ANSALDO reserves the right to change any data given in this data sheet at any time without previous notice.

If not stated otherwise the maximum value of ratings (symbols over shaded background) and characteristics is reported.

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